

3-phase bridge inverter

SKiiP 25AC126V1

#### **Features**

- Fast Trench IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

### Typical Applications\*

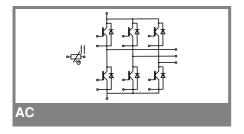
- Inverter up to 28 kVA
- Typical motor power 15 kW

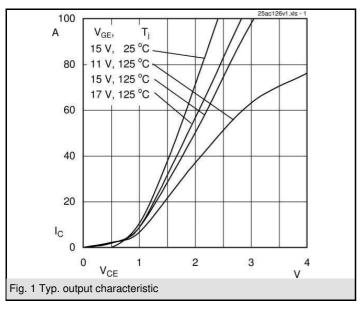
#### **Remarks**

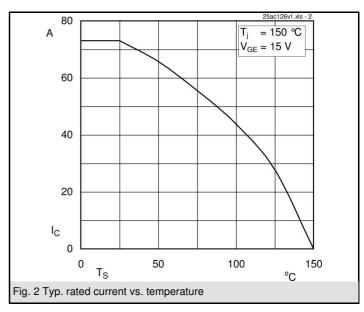
• V<sub>CEsat</sub> , V<sub>F</sub> = chip level value

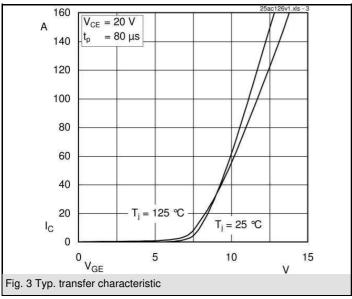
Absolute	Maximum Ratings	s = 25 °C, unless otherwise specified						
Symbol	Conditions	Values	Units					
IGBT - Inverter								
$V_{CES}$		1200	V					
I <sub>C</sub>	T <sub>s</sub> = 25 (70) °C	73 (55)	Α					
I <sub>CRM</sub>	$t_p \le 1 \text{ ms}$	100	Α					
$V_{GES}$	·	± 20	V					
T <sub>j</sub>		- 40 <b>+</b> 150	°C					
Diode - Inverter								
I <sub>F</sub>	T <sub>s</sub> = 25 (70) °C	62 (46)	Α					
I <sub>FRM</sub>	$t_p \le 1 \text{ ms}$	100	Α					
T <sub>j</sub>		- 40 <b>+</b> 150	°C					
I <sub>tRMS</sub>	per power terminal (20 A / spring)	100	Α					
T <sub>stg</sub>	$T_{op} \leq T_{stg}$	- 40 <b>+</b> 125	°C					
V <sub>isol</sub>	AC, 1 min.	2500	V					

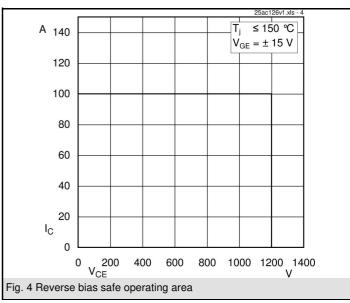
Character	istics	T <sub>s</sub> = 25 °C,	s = 25 °C, unless otherwise specified					
	Conditions	min.	typ.	max.	Units			
IGBT - Inverter								
V <sub>CEsat</sub> V <sub>GE(th)</sub> V <sub>CE(TO)</sub> r <sub>T</sub> C <sub>ies</sub> C <sub>oes</sub>	$\begin{split} &I_{\text{Cnom}} = 50 \text{ A, } T_{\text{j}} = 25 \text{ (125) °C} \\ &V_{\text{GE}} = V_{\text{CE}}, I_{\text{C}} = 2 \text{ mA} \\ &T_{\text{j}} = 25 \text{ (125) °C} \\ &T_{\text{j}} = 25 \text{ (125) °C} \\ &V_{\text{CE}} = 25 \text{ V, } V_{\text{GE}} = 0 \text{ V, f} = 1 \text{ MHz} \\ &V_{\text{CE}} = 25 \text{ V, } V_{\text{GE}} = 0 \text{ V, f} = 1 \text{ MHz} \end{split}$	5	1,7 (2) 5,8 1 (0,9) 14 (22) 3,7 0,8	2,1 (2,4) 6,5 1,2 (1,1) 18 (26)	V V V mΩ nF nF			
C <sub>res</sub>	V <sub>CE</sub> = 25 V, V <sub>GE</sub> = 0 V, f = 1 MHz per IGBT		0,7 0,55		nF K/W			
$\begin{aligned} &R_{th(j\text{-}s)} \\ &t_{d(on)} \\ &t_{r} \\ &t_{d(off)} \\ &t_{f} \\ &E_{on} \\ &E_{off} \end{aligned}$	under following conditions $V_{CC}$ = 600 V, $V_{GE}$ = ± 15 V $I_{Cnom}$ = 50 A, $T_{j}$ = 125 °C $R_{Gon}$ = $R_{Goff}$ = 12 $\Omega$ inductive load		85 30 440 90 5,8 6,5		ns ns ns ns mJ mJ			
$V_F = V_{EC}$ $V_{(TO)}$ $r_T$ $R_{th(j-s)}$	I <sub>Fnom</sub> = 50 A, T <sub>j</sub> = 25 (125) °C T <sub>j</sub> = 25 (125) °C T <sub>j</sub> = 25 (125) °C per diode		1,6 (1,6) 1 (0,8) 12 (16) 1	1,8 (1,8) 1,1 (0,9) 14 (18)	V V mΩ K/W			
I <sub>RRM</sub> Q <sub>rr</sub> E <sub>rr</sub>	under following conditions $I_{Fnom} = 50 \text{ A}, V_R = 600 \text{ V}$ $V_{GE} = 0 \text{ V}, T_j = 125 \text{ °C}$ $di_F/dt = 1900 \text{ A/µs}$		71 11,5 5,1		Α μC mJ			
Temperature Sensor								
R <sub>ts</sub>	3 %, T <sub>r</sub> = 25 (100) °C		1000(1670)		Ω			
Mechanica m M <sub>s</sub>	Al Data  Mounting torque	2	65	2,5	g Nm			

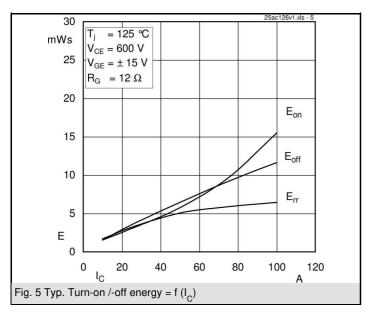


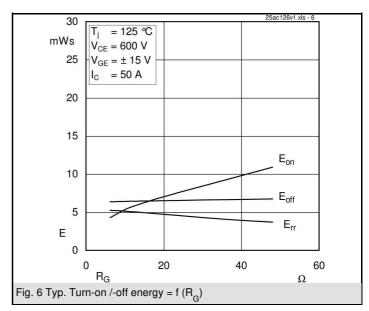


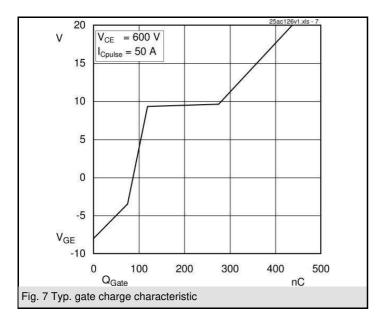


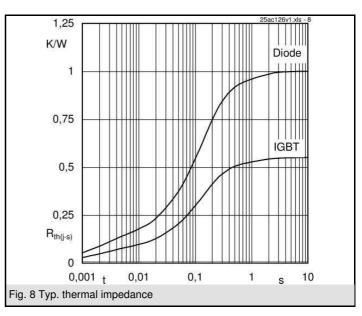


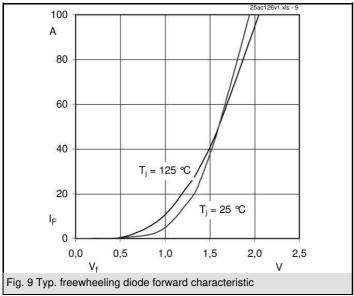


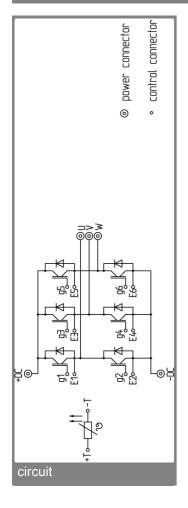


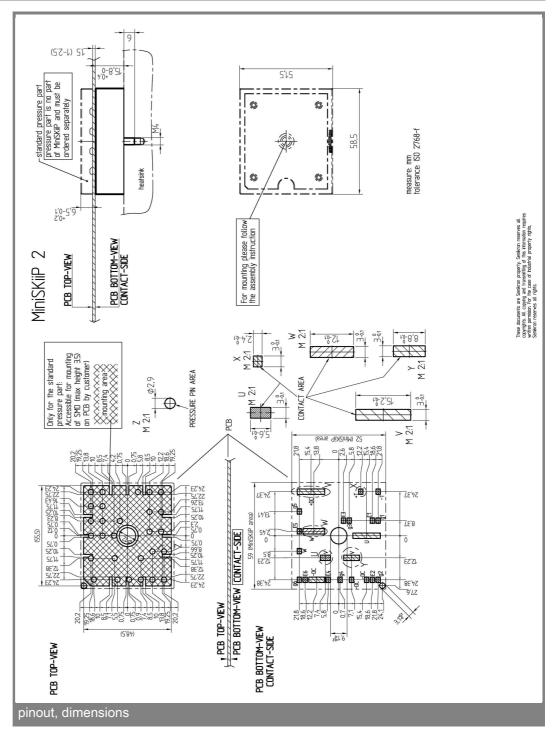












This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

<sup>\*</sup> The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.